

Homework 4

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Problem 1 In this problem we will introduce another way to think about Hall conductance. As discussed in class, the edge of a Chern insulator with Chern number n should have n chiral edge modes. Suppose that the n edge modes move one way near the $y = 0$ edge, and the opposite way at the $y = L_y$ edge. 1. First consider the $y = L_y$ edge. Each of the n edge modes near $y = L_y$ can be modeled as a non-interacting free fermion model $H = \sum_k (\epsilon_{1k} - \mu_1) c_k^\dagger c_k$, where ϵ_{1k} is a monotonically increasing function of k , μ_1 corresponds to the chemical potential at the $y = L_y$ edge. We assume that the infinitely many states with $\epsilon_{1k} < \mu_1$ are all filled (in reality, the limit $k \rightarrow -\infty$ corresponds to moving into the bulk, and k is cut off accordingly). Suppose one changes the chemical potential $\mu_1 \rightarrow \mu_1 + \Delta\mu_1$. What is the corresponding change ΔI_1 in the $y = L_y$ edge current? (Include all n edge modes). 2. Now consider the $y = 0$ edge mode, modeled by n chiral modes of the form $H = \sum_k (\epsilon_{2k} - \mu_2) c_k^\dagger c_k$, where ϵ_{2k} is a monotonically decreasing function of k . What is the corresponding change ΔI_2 in the $y = 0$ edge current if one changes the chemical potential $\mu_2 \rightarrow \mu_2 + \Delta\mu_2$? 3. Find the total current $I = I_1 + I_2$ induced by a chemical potential difference $\mu_1 - \mu_2 = \Delta\mu$ between the two edges, assuming that $I = 0$ when $\mu_1 = \mu_2$. Interpret your result in terms of the Hall conductance σ_H . 4. Now repeat the calculation at finite temperature T . Show that the edge currents and the Hall conductance do not change. (In reality, there is a temperature dependence coming from thermal activation above the bulk gap Δ , but it is exponentially small $\sim e^{-\Delta/T}$).

Solution The problem is illustrated in Figure 1.

(a) The current is

$$\begin{aligned} I_1 &= -e \cdot \text{density of states} \cdot \text{cross section} \cdot v \\ &= -e \frac{1}{L} \sum_{\text{occupied states}} \frac{1}{\hbar} \frac{\partial \epsilon_{1k}}{\partial k} = -\frac{e}{\hbar} \frac{n}{L} \sum_{\Lambda_1 \leq k \leq k_{1F}} \frac{\partial \epsilon_{1k}}{\partial k} = -n \frac{e}{\hbar} \int_{\Lambda_1}^{k_{1F}} \frac{dk}{2\pi} \frac{\partial \epsilon_{1k}}{\partial k} \\ &= -n \frac{e}{\hbar} (\epsilon_{1F} - \epsilon_{1,k=\Lambda_1}) = -n \frac{e}{\hbar} (\mu_1 - \epsilon_{1,k=\Lambda_1}). \end{aligned} \quad (1)$$

So we have

$$\Delta I_1 = -n \frac{e}{\hbar} \Delta\mu_1. \quad (2)$$

(b) Similarly, we have

$$\begin{aligned} I_2 &= -e \cdot \text{density of states} \cdot \text{cross section} \cdot v \\ &= -e \frac{1}{L} \sum_{\text{occupied states}} \frac{1}{\hbar} \frac{\partial \epsilon_{1k}}{\partial k} = -\frac{e}{\hbar} \frac{n}{L} \sum_{k_{2F} \leq k \leq \Lambda_2} \frac{\partial \epsilon_{2k}}{\partial k} = -n \frac{e}{\hbar} \int_{k_{2F}}^{\Lambda_2} \frac{dk}{2\pi} \frac{\partial \epsilon_{2k}}{\partial k} \\ &= -n \frac{e}{\hbar} (\epsilon_{2,k=\Lambda_2} - \epsilon_{2F}) = -n \frac{e}{\hbar} (\epsilon_{2,k=\Lambda_2} - \mu), \end{aligned} \quad (3)$$

and

$$\Delta I_2 = n \frac{e}{\hbar} \Delta\mu_2. \quad (4)$$

(c) We have

$$I = -n \frac{e}{\hbar} (\mu_1 - \mu_2 + \epsilon_{2,k=\Lambda_2} - \epsilon_{1,k=\Lambda_1}). \quad (5)$$

When $\Delta\mu = 0$, we have $I = 0$, so we find the two cutoff terms cancel each other, and

$$I = -n \frac{e}{\hbar} \Delta\mu. \quad (6)$$

In a Hall effect setting, the difference of the chemical potentials arises from the external electric field: conservation of energy tells us

$$\mu_1 - eU = \mu_2, \quad (7)$$

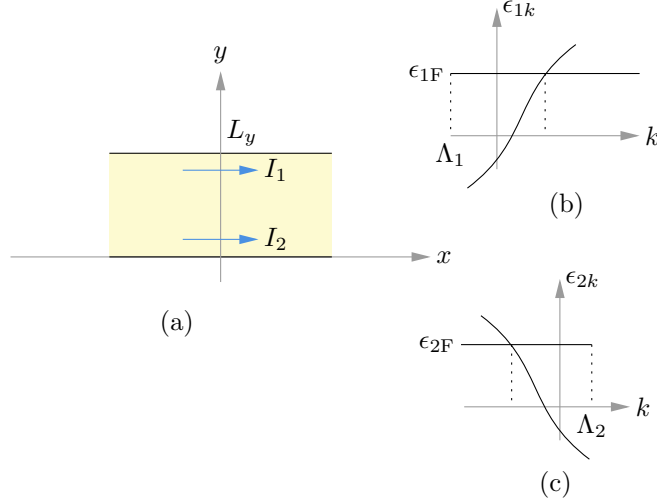


Figure 1: Boundary modes of a 2D Chern insulator (a) The device and sign conventions (b) The spectrum of the boundary modes at $y = L_y$, where Λ_1 is a momentum cutoff (c) The spectrum of the boundary modes at $y = 0$, where Λ_2 is a momentum cutoff

and therefore

$$I = -n \frac{e}{h} \cdot eU = -n \underbrace{\frac{e^2}{h}}_{1/R_H} U. \quad (8)$$

So we get the expected quantized conductance.

(d) Ignoring excited bulk modes, we have

$$\begin{aligned} I_1 &= -n \frac{e}{h} \int_{\Lambda_1}^{\infty} \frac{dk}{2\pi} \frac{1}{1 + e^{(\epsilon_{1k} - \mu_1)/k_B T}} \frac{\partial \epsilon_{1k}}{\partial k} \\ &= -n \frac{e}{h} \int_{\epsilon_{1,k=\Lambda_1} - \mu_1}^{\infty} d\xi \frac{1}{1 + e^{\xi/k_B T}}, \end{aligned} \quad (9)$$

and similarly

$$\begin{aligned} I_2 &= -n \frac{e}{h} \int_{-\infty}^{\Lambda_2} \frac{dk}{2\pi} \frac{1}{1 + e^{(\epsilon_{2k} - \mu_2)/k_B T}} \frac{\partial \epsilon_{2k}}{\partial k} \\ &= -n \frac{e}{h} \int_{\infty}^{\epsilon_{2,k=\Lambda_2} - \mu_2} d\xi \frac{1}{1 + e^{\xi/k_B T}} = n \frac{e}{h} \int_{\epsilon_{2,k=\Lambda_2} - \mu_2}^{\infty} d\xi \frac{1}{1 + e^{\xi/k_B T}}, \end{aligned} \quad (10)$$

and therefore

$$I = -n \frac{e}{h} \int_{\epsilon_{1,k=\Lambda_1} - \mu_1}^{\epsilon_{2,k=\Lambda_2} - \mu_2} \frac{d\xi}{1 + e^{\xi/k_B T}}. \quad (11)$$

Since the Fermi-Dirac distribution function is always positive, the condition that when $\Delta\mu = 0$, $I = 0$ implies $\epsilon_{1,k=\Lambda_1} = \epsilon_{2,k=\Lambda_2} =: \epsilon_{\Lambda}$, so we have

$$I = -n \frac{e}{h} \int_{\epsilon_{\Lambda} - \mu_1}^{\epsilon_{\Lambda} - \mu_2} \frac{d\xi}{1 + e^{\xi/k_B T}}. \quad (12)$$

Since Λ must be large, a very good approximation is

$$I = -n \frac{e}{h} \Delta\mu = -n \frac{e^2}{h} U, \quad (13)$$

so the edge current and the Hall conductance are not affected much by a finite T .

Problem 2

Solution

(a) The only change we need to do is to replace the electric charge $-e$ by the “energy charge” ϵ_k , and following the line of reasoning in Problem 1 (d), we have

$$\begin{aligned} I_{Q1} &= \frac{n}{h} \int_{\epsilon_{1,k=\Lambda_1}}^{\infty} d\epsilon \frac{1}{1 + e^{(\epsilon - \mu_1)/k_B T_1}} \epsilon \\ &= k_B T_1 \frac{n}{h} \left(k_B T_1 \int_{\frac{\epsilon_{1,k=\Lambda_1} - \mu}{k_B T_1}}^{\infty} dx \frac{x}{1 + e^x} + \mu \int_{\frac{\epsilon_{1,k=\Lambda_1} - \mu}{k_B T_1}}^{\infty} dx \frac{1}{1 + e^x} \right), \end{aligned} \quad (14)$$

and similarly

$$I_{Q2} = -k_B T_2 \frac{n}{h} \left(k_B T_2 \int_{\frac{\epsilon_{2,k=\Lambda_2} - \mu}{k_B T_2}}^{\infty} dx \frac{x}{1 + e^x} + \mu \int_{\frac{\epsilon_{2,k=\Lambda_2} - \mu}{k_B T_2}}^{\infty} dx \frac{1}{1 + e^x} \right). \quad (15)$$

The sign difference between I_{Q1} and I_{Q2} comes in the same way of (10). Again, when $T_1 = T_2$, we need $I = I_{Q1} + I_{Q2} = 0$, so $\epsilon_{1,k=\Lambda_1} = \epsilon_{2,k=\Lambda_2} =: \epsilon_{\Lambda}$.

(b) We have

$$\int_t^{\infty} dx \frac{1}{1 + e^x} = 2 \operatorname{arctanh}(1 + 2e^t), \quad (16)$$

$$\int_t^{\infty} dx \frac{x}{1 + e^x} = t \ln(1 + e^{-t}) - \operatorname{Li}_2(-e^{-t}). \quad (17)$$